

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	122	(capacitor-less or capacitorless or (capacitor adj less)) adj5 (memory or cell or DRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 17:51
L3	82860	wordline or (word adj line) or rowline or (row adj line)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:24
L4	3505	(unselect\$4 or (non adj select\$4)) adj2 L3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:25
L8	13	4 and 2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 17:53
L9	1195	(body near5 float\$4) near5 (DRAM or cell or memory or transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:24
L10	261936	increas\$8 near5 (voltage or potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:27
L11	34	9 with 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:03
L12	140	4 with 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:09
L19	38	4 and 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:08
L20	1993697	(writ\$ or program\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:09
L21	329	4 same 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:22
L22	180	20 same 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10

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L23	4190	365/149	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10
L24	236	365/150	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10
L25	1257	365/174	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10
L26	1786	365/182	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10
L27	960	365/184	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:10
L28	157	365/186	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:12
L29	176	9 and "365".clas.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:12
L30	25	4 and 29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:13
L40	15	21 and 23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21
L41	0	21 and 24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21
L42	7	21 and 25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21
L43	11	21 and 26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21

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L44	3	21 and 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21
L45	0	21 and 28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/25 18:21
L47	8	(4 same 10).clm.	US-PGPUB	OR	ON	2006/02/25 18:22
L48	93	((body near5 float\$4) near5 (DRAM or cell or memory or transistor)).clm.	US-PGPUB	OR	ON	2006/02/25 18:24
L50	2042	((unselect\$4 or (non adj select\$4))).clm.	US-PGPUB	OR	ON	2006/02/25 18:25
L51	5890	(wordline or (word adj line) or rowline or (row adj line)).clm.	US-PGPUB	OR	ON	2006/02/25 18:26
L52	436	50 and 51	US-PGPUB	OR	ON	2006/02/25 18:26
L53	3	48 and 52	US-PGPUB	OR	ON	2006/02/25 18:26
L54	3731	(increas\$8 near5 (voltage or potential)).clm.	US-PGPUB	OR	ON	2006/02/25 18:27
L55	33	52 and 54	US-PGPUB	OR	ON	2006/02/25 18:27